# RadHard-by-Design Analog RHD5904



Quad Instrumentation Amplifier with Enable Advanced Datasheet Cobham.com/HiRel December 16, 2016

The most important thing we build is trust

#### **FEATURES**

Single power supply operation (3.3V to	5.0V) or dual power supply operation ( $\pm 1.65$ to $\pm 2.5$ V)		
Radiation performance			
- Total dose:	>1 Mrad(Si); Dose rate = $50-300$ rad(Si)/s		
- ELDRS Immune			
- SEL Immune	>100 MeV-cm <sup>2</sup> /mg >10 <sup>14</sup> neutrons/cm <sup>2</sup>		
- Neutron Displacement Damage	>10 <sup>14</sup> neutrons/cm <sup>2</sup>		
High Speed			
Rail-to-Rail input and output range			
Enable pin to Enable/Disable amplifiers	in pairs.		
Short Circuit Tolerant			
Full military temperature range			
Designed for aerospace and high reliabil	ity space applications		
Packaging – Hermetic ceramic SOIC			
- 16-pin, .417"L x .300"W x 0.120"Ht	SOIC		
- Typical Weight 0.8 grams			

☐ Radiation Hardness Assurance Plan: DLA Certified to MIL-PRF-38534, Appendix G.

# **GENERAL DESCRIPTION**

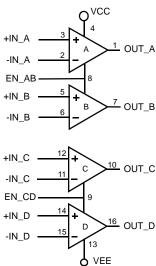
The RHD5904 is a radiation hardened, single supply, high speed, quad operational amplifier with enable in a 16-pin SOIC package. The RHD5904 design uses specific circuit topology and layout methods to mitigate total ionizing dose effects and single event latchup. These characteristics make the RHD5904 especially suited for the harsh environment encountered in Deep Space missions. It is guaranteed operational from -55°C to +125°C. Available screened in accordance with MIL-PRF-38534 Class K, the RHD5904 is ideal for demanding military and space applications.

#### **ORGANIZATION AND APPLICATION**

The RHD5904 amplifiers are capable of rail-to-rail input and outputs. Performance characteristics listed are for general purpose operational 5V CMOS amplifier applications. The amplifiers will drive substantial resistive or capacitive loads and are unity gain stable under normal conditions. Resistive loads in the low kohm range can be handled without gain derating and capacitive loads of several nF can be tolerated. CMOS device drive has a negative temperature coefficient and the devices are therefore inherently tolerant to momentary shorts, although on chip thermal shutdown is not provided. All inputs and outputs are diode protected.

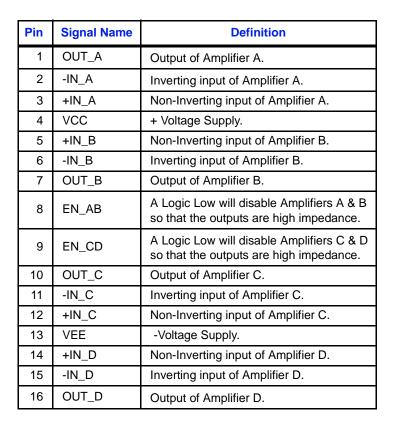
The devices will not latch with SEU events to above  $100 \text{ MeV-cm}^2/\text{mg}$ . Total dose degradation is minimal to above 1 Mrad(Si). Displacement damage environments to neutron fluence equivalents in the mid  $10^{14}$  neutrons per cm<sup>2</sup> range are readily tolerated. There is no sensitivity to low-dose rate (ELDRS) effects. SEU effects are application dependent.

The RHD5904 is configured with enable/disable control. Pairs of amplifiers are put in a power-down condition with their outputs in a high impedance state. Several useful operational amplifier configurations are supported where more than one amplifier can feed an output with others disabled.

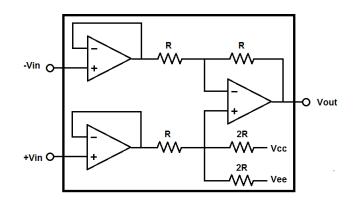


**FIGURE 1: BLOCK DIAGRAM** 

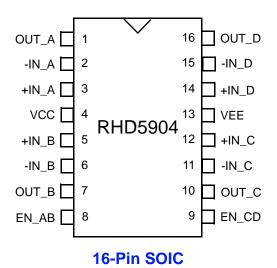
- 1. Package and lid are electrically isolated from signal pads.
- 2. EN\_AB enables amplifiers A & B. EN\_CD enables amplifiers C & D.



**TABLE 1: PIN-OUT DESCRIPTION** 



**FIGURE 1A: SECTION DIAGRAM** 



**FIGURE 2: PACKAGE PIN-OUT** 

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Notes:

### **ABSOLUTE MAXIMUM RATINGS**

Parameter	Range	Units
Case Operating Temperature Range	-55 to +125	°C
Storage Temperature Range	-65 to +150	°C
Junction Temperature	+150	°C
Supply Voltage Vcc - VEE	+7.0	V
Input Voltage	VCC +0.4 VEE -0.4	V
Input Current	±10	mA
Lead Temperature (soldering, 10 seconds)	300	°C
Thermal Resistance, Junction to Case, Θjc	7	°C/W
Power @ 25°C	200	mW

NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress rating only; functional operation beyond the "Operation Conditions" is not recommended and extended exposure beyond the "Operation Conditions" may affect device reliability.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Typical	Units
+Vcc	Power Supply Voltage	3.3 to 5.0	V
Vсм	Input Common Mode Range	VCC to VEE	V

# **ELECTRICAL PERFORMANCE CHARACTERISTICS**

(TC = -55°C TO +125°C, +VCC = +5.0V -- UNLESS OTHERWISE SPECIFIED)

Parameter	Symbol	Conditions	Min	Max	Units
Input Offset Voltage	Vos		-2	2	mV
Input Offset Current	los		-10	10	рА
Input Bias Current	lв		-20	20	рА
Input Offset TempCo 2/	Viost			10	uV/C
Common Mode Rejection Ratio	CMRR		70		dB
Power Supply Rejection Ratio	PSRR		70		dB
Output Voltage High	Voн	ROUT = 3.6 Kohms to GND	4.9		V
Output Voltage Low	Vol	ROUT = 3.6 Kohms to VCC		0.1	V
Short Circuit	Io(sink)	Vout to Vcc	-63		mA
Output Current 2/	Io(source)	VOUT to VEE		45	mA
Slew Rate	SR	RL = 8K	2.5		V/uS
Open Loop Gain 2/	Aol	No Load	100		dB
Unity Gain Bandwidth	UGBW	RL = 10K	5		MHz

# **ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)**

(TC =  $-55^{\circ}$ C TO  $+125^{\circ}$ C, +VCC = +5.0V -- UNLESS OTHERWISE SPECIFIED)

Parameter	Symbol	Conditions	Min	Max	Units
Input Voltage - Enable (EN_AB,	Vні	High (Enabled)	70% VCC - VEE		V
EN_CD)	VLO	Low (Disabled)		30% VCC - VEE	V
Input Current - Enable (EN_AB, EN_CD)	lEN			100	nA
Quiagant Supply Current	looo	All Amplifiers Enabled, No Load		5.5	mA
Quiescent Supply Current	Iccq	All Amplifier Disabled		1	uA
Channel Separation 2/		RL = 2K, f = 1.0KHz	90		dB
Input-Referred Voltage Noise 2/	e <sub>n</sub>	F = 1 kHz		TBD	$V/\sqrt{Hz}$
Phase Margin 2/	$\Phi_{m}$		TBD		Deg

#### Notes:

- 1/ Specification derated to reflect Total Dose exposure to 1 Mrad(Si) @ +25°C.
- 2/ Not tested. Shall be guaranteed by design, characterization, or correlation to other test parameters.

### **SWITCHING CHARACTERISTICS**

(TC = -55°C TO +125°C, +VCC = +5.0V -- UNLESS OTHERWISE SPECIFIED)

Parameter	Symbol	Conditions	Min	Max	Units
Output Delay (Enabled)	t <sub>ON</sub> EN			100	ns
Output Delay (Disabled)	t <sub>OFF</sub> EN			100	ns

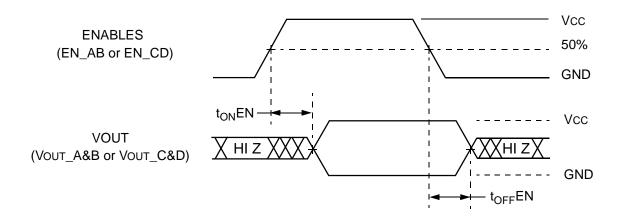
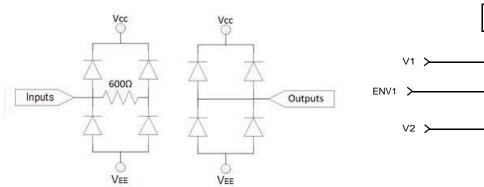


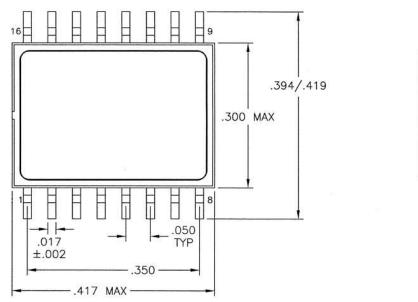
FIGURE 3: RHD5904 SWITCHING DIAGRAM

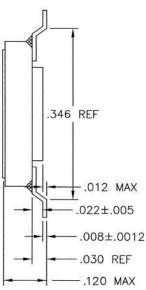
# Multiple Amplifiers - Selectable Output



**FIGURE 4: PROTECTION DIODES** 

APPLICATION NOTE: MULTIPLE AMPLIFIERS





Note: Package and lid are electrically isolated from signal pads.

## FIGURE 5: PACKAGE OUTLINE

# **ORDERING INFORMATION**

Model DLA SMD #		Screening	Package
RHD5904-7	-	Commercial Flow, +25°C testing only	
RHD5904-S	-	Military Temperature, -55°C to +125°C - Screened in accordance with the individual Test Methods of MIL-STD-883 for Space Applications	
RHD5904-201-1S	5962-1221301KXC	DLA SMD Pending	16-pin SOIC Package
RHD5904-201-2S	5962-1221301KXA	DEA SIMD I enaing	ooro r donago
RHD5904-901-1S	5962H1221301KXC	DLA SMD and Radiation Certification Pending	
RHD5904-901-2S	5962H1221301KXA	DEA SIMD and Radiation Certification Femaling	

# **REVISION HISTORY**

Date	Revision	Change Description
12/16/2016	В	Import into Cobham format. Update package height dimension, add figure 1a section diagram, update absolute max supply voltage, add absolute max input current, remove ESR rating, remove 'Typ' column, revise application notes, add protection diode figure, update the SMD number, update export statement.
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#### Datasheet Definition

Advanced Datasheet - Product In Development

Preliminary Datasheet - Shipping Prototype

Datasheet - Shipping QML & Reduced Hi-Rel



#### **EXPORT CONTROL:**

This product is controlled for export under the Export Administration Regulations (EAR), 15 CFR Parts 730-774.

A license from the Department of Commerce may be required prior to the export of this product from the United States.

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